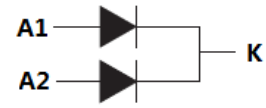
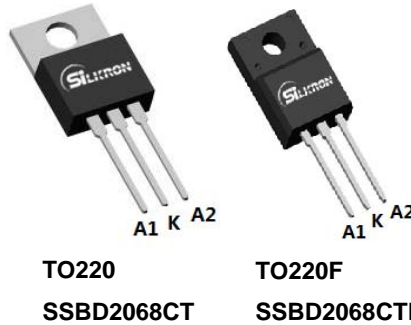


Main Product Characteristics:

IF	2×10A
VRRM	68V
Tj(max)	150°C
Vf(max)	0.65V


Schematic Diagram
Features and Benefits:

- High Junction Temperature
- High ESD Protection
- High Forward & Reverse Surge capability


Description:

Schottky Barrier Rectifier designed for high frequency switch model power supplies such as adaptors and DC/DC converters; this product special design for high forward and reverse surge capability

Absolute Rating:

Symbol	Characterizes	Value	Unit
VRRM	Peak Repetitive Reverse Voltage	68	V
VR(RMS)	RMS Reverse Voltage	47.6	V
IF(AV)	Average Forward Current	Per diode	10 A
		Per device	20 A
IFSM	Non Repetitive Surge Forward Current(tp=8.3ms sinusoidal)	180	A
IRRM	Peak Repetitive Reverse Surge Current(Tp=2us)	2	A
TJ	Maximum operation Junction Temperature Range	-55~150	°C
Tstg	Storage Temperature Range	-55~150	°C

Thermal Resistance

Symbol	Characterizes	Value	Unit
RθJC	Maximum Thermal Resistance Junction To Case(per leg)	2	°C/W
RθJC	Case(per leg)	4	°C/W

Electrical Characterizes @TA=25°C unless otherwise specified

Symbol	Characterizes	Min	Typ	Max	Unit	Test Condition
VR	Reverse Breakdown Voltage	68			V	IR=0.5mA
VF	Forward Voltage Drop			0.65	V	IF=10A, TJ=25°C
				0.6		IF=10A, TJ=125°C
IR	Leakage Current			0.2	mA	VR=68V, TJ=25°C
				50		VR=68V, TJ=125°C

I-V Curves:

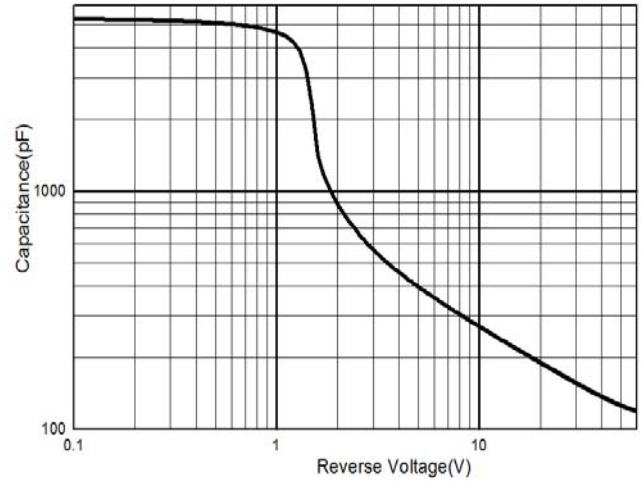
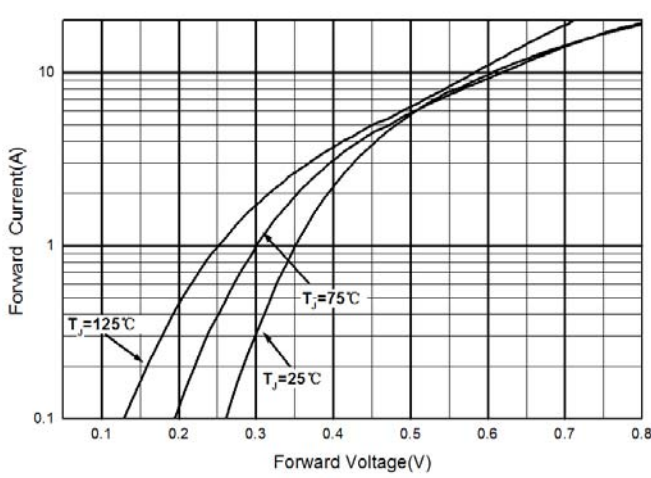


Figure 1: Typical Forward Characteristics

Figure 2: Typical Capacitance Characteristics

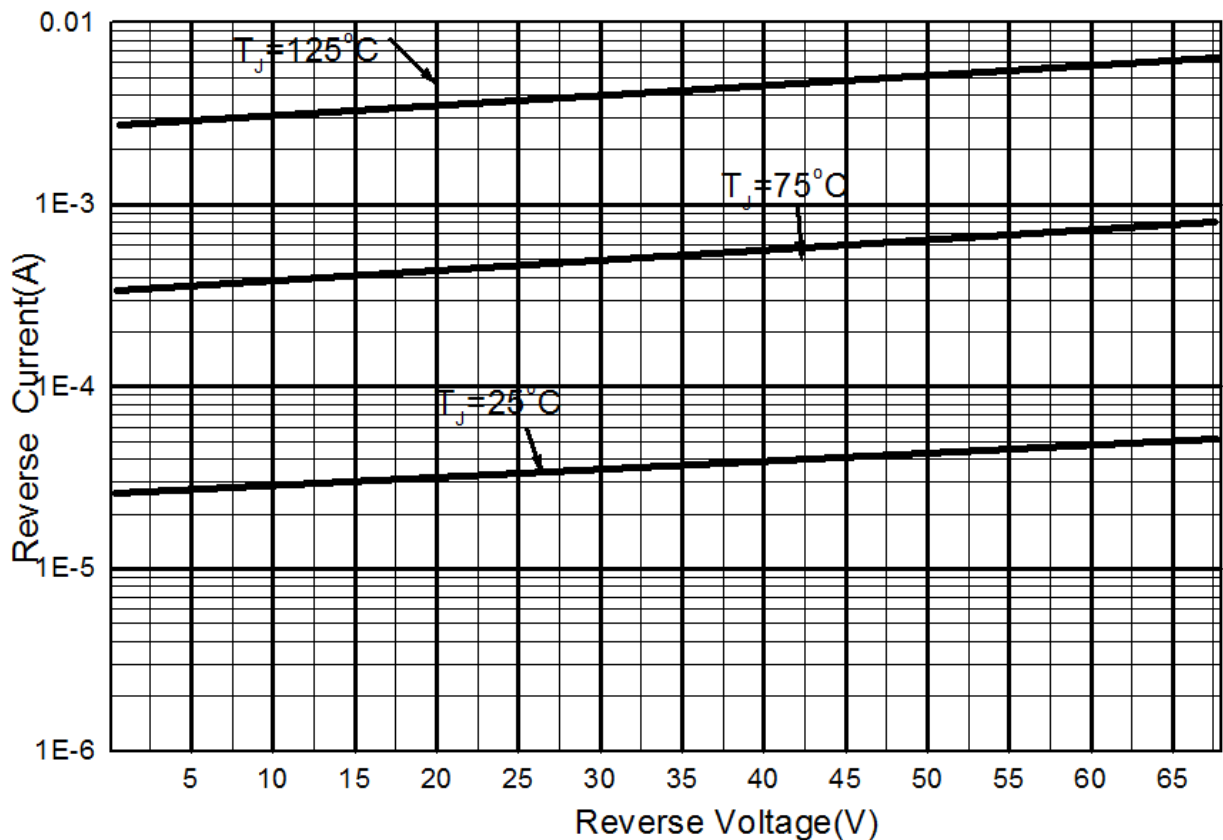
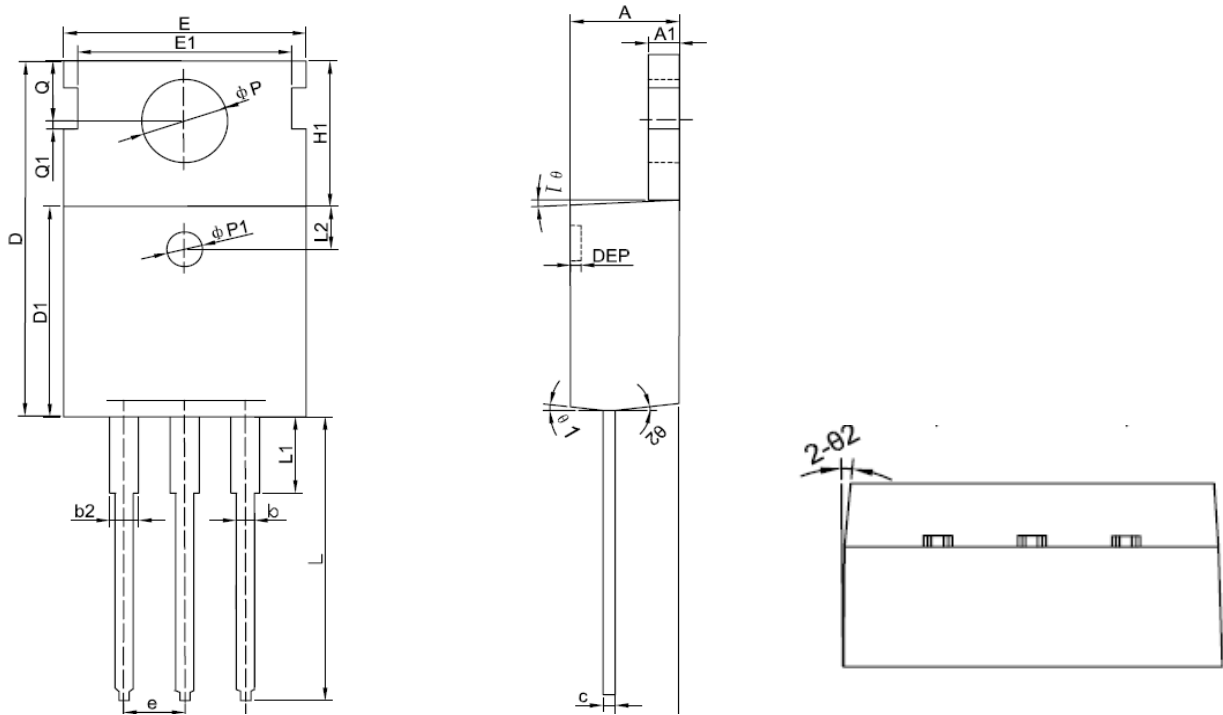
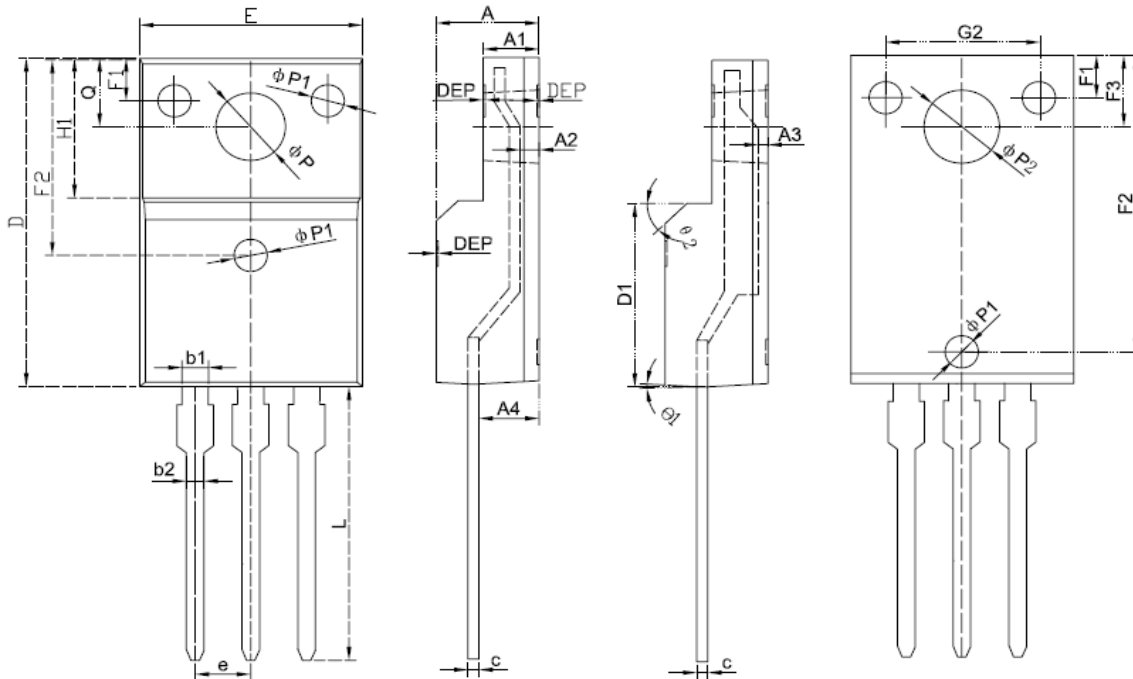


Figure 3: Typical Reverse Characteristics

Mechanical Data:
TO220:


Symbol	Dimension In Millimeters			Dimension In Inches		
	Min	Nom	Max	Min	Nom	Max
A	4.400	4.550	4.700	0.173	0.179	0.185
A1	1.270	1.300	1.330	0.050	0.051	0.052
A2	2.590	2.690	2.790	0.102	0.106	0.110
b	0.770	-	0.900	0.030	-	0.035
b2	1.230	-	1.360	0.048	-	0.054
c	0.480	0.500	0.520	0.019	0.020	0.020
D	15.100	15.400	15.700	-	0.606	-
D1	9.000	9.100	9.200	0.354	0.358	0.362
DEP	0.050	0.285	0.520	0.002	0.011	0.020
E	10.060	10.160	10.260	0.396	0.400	0.404
E1	-	8.700	-	-	0.343	-
ϕP1	1.400	1.500	1.600	0.055	0.059	0.063
e	2.54BSC			0.1BSC		
e1	5.08BSC			0.2BSC		
H1	6.100	6.300	6.500	0.240	0.248	0.256
L	12.750	12.960	13.170	0.502	0.510	0.519
L1	-	-	3.950	-	-	0.156
L2	1.85REF			0.073REF		
ϕP	3.570	3.600	3.630	0.141	0.142	0.143
Q	2.730	2.800	2.870	0.107	0.110	0.113
Q1	-	0.200	-	-	0.008	-
θ1	5°	7°	9°	5°	7°	9°
θ2	1°	3°	5°	1°	3°	5°

TO220F:


Symbol	Dimension In Millimeters			Dimension In Inches		
	Min	Nom	Max	Min	Nom	Max
E	9.960	10.160	10.360	0.392	0.400	0.408
A	4.500	4.700	4.900	0.177	0.185	0.193
A1	2.340	2.540	2.740	0.092	0.100	0.108
A2	0.950	1.050	1.150	0.037	0.041	0.045
A3	0.420	0.520	0.620	0.017	0.020	0.024
A4	2.650	2.750	2.850	0.104	0.108	0.112
c	-	0.500	-	-	0.020	-
D	15.670	15.870	16.070	0.617	0.625	0.633
Q	3.200	3.300	3.400	0.126	0.130	0.134
H1	6.480	6.680	6.880	0.255	0.263	0.271
e	2.54BSC			0.10BSC		
ϕP	-	3.183	-	-	0.125	-
L	12.780	12.980	13.180	0.503	0.511	0.519
D1	8.990	9.190	9.390	0.354	0.362	0.370
ϕP1	1.400	1.500	1.600	0.055	0.059	0.063
ϕP2	-	3.450	-	-	0.136	-
ϑ1	4°	5°	6°	4°	5°	6°
ϑ2	-	45°	-	-	45°	-
DEP	0.050	0.100	0.150	0.002	0.004	0.006
F1	1.900	2.000	2.100	0.075	0.079	0.083
F2	8.980	9.180	9.380	0.354	0.361	0.369
F3	3.200	3.300	3.400	0.126	0.130	0.134
G2	6.900	7.000	7.100	0.272	0.276	0.280
b1	1.170	1.205	1.240	0.046	0.047	0.049
b2	0.770	0.810	0.850	0.030	0.032	0.033

Ordering and Marking Information
Device Marking: SSBD2068CT&SSBD2068CTF
Package (Available)
TO-220&TO220F
Operating Temperature Range
C : -55 to 150 °C
Devices per Unit

Package Type	Units/Tube	Tubes/Inner Box	Units/Inner Box	Inner Boxes/Carton Box	Units/Carton Box
TO220	50	20	1000	6	6000
TO220F	50	20	1000	6	6000

Reliability Test Program

Test Item	Conditions	Duration	Sample Size
High Temperature Reverse Bias(HTRB)	Tj=125°C to 175°C @ 80% of Max VDSS/VCES/VR	168 hours 500 hours 1000 hours	3 lots x 77 devices

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